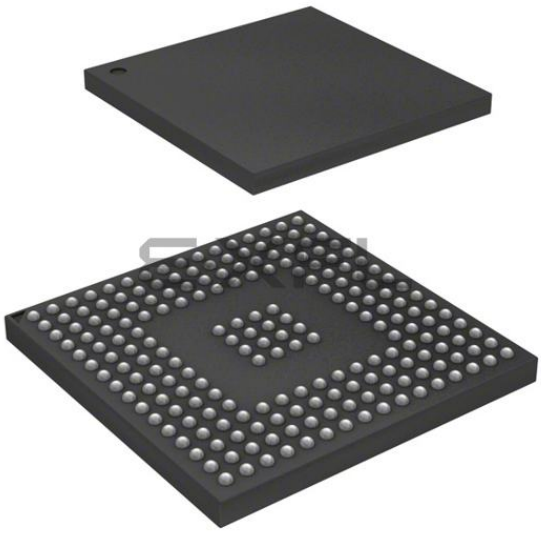

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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	e200z4
Core Size	32-Bit Single-Core
Speed	80MHz
Connectivity	CANbus, EBI/EMI, LINbus, SCI, SPI
Peripherals	DMA, POR, PWM, WDT
Number of I/O	120
Program Memory Size	4MB (4M x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	192K x 8
Voltage - Supply (Vcc/Vdd)	1.14V ~ 5.25V
Data Converters	A/D 40x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	208-BGA
Supplier Device Package	208-BGA (17x17)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/spc5644af0mmg3r

1.4.5 Memory protection unit (MPU)

The Memory Protection Unit (MPU) provides hardware access control for all memory references generated in a device. Using preprogrammed region descriptors, which define memory spaces and their associated access rights, the MPU concurrently monitors all system bus transactions and evaluates the appropriateness of each transfer. Memory references with sufficient access control rights are allowed to complete; references that are not mapped to any region descriptor or have insufficient rights are terminated with a protection error response.

The MPU has these major features:

- Support for 16 memory region descriptors, each 128 bits in size
  - Specification of start and end addresses provide granularity for region sizes from 32 bytes to 4 GB
  - MPU is invalid at reset, thus no access restrictions are enforced
  - Two types of access control definitions: processor core bus master supports the traditional {read, write, execute} permissions with independent definitions for supervisor and user mode accesses; the remaining non-core bus masters (eDMA, FlexRay, and EBI[1]) support {read, write} attributes
  - Automatic hardware maintenance of the region descriptor valid bit removes issues associated with maintaining a coherent image of the descriptor
  - Alternate memory view of the access control word for each descriptor provides an efficient mechanism to dynamically alter the access rights of a descriptor only[1]
  - For overlapping region descriptors, priority is given to permission granting over access denying as this approach provides more flexibility to system software
- Support for two XBAR slave port connections (SRAM and PBRIDGE)
  - For each connected XBAR slave port (SRAM and PBRIDGE), MPU hardware monitors every port access using the pre-programmed memory region descriptors
  - An access protection error is detected if a memory reference does not hit in any memory region or the reference is flagged as illegal in all memory regions where it does hit. In the event of an access error, the XBAR reference is terminated with an error response and the MPU inhibits the bus cycle being sent to the targeted slave device
  - 64-bit error registers, one for each XBAR slave port, capture the last faulting address, attributes, and detail information

1.4.6 FMPLL

The FMPLL allows the user to generate high speed system clocks from a 4 MHz to 40 MHz crystal oscillator or external clock generator. Further, the FMPLL supports programmable frequency modulation of the system clock. The PLL multiplication factor, output clock divider ratio are all software configurable. The PLL has the following major features:

- Input clock frequency from 4 MHz to 40 MHz
- Reduced frequency divider (RFD) for reduced frequency operation without forcing the PLL to relock
- Three modes of operation
  - Bypass mode with PLL off
  - Bypass mode with PLL running (default mode out of reset)
  - PLL normal mode
- Each of the three modes may be run with a crystal oscillator or an external clock reference
- Programmable frequency modulation
  - Modulation enabled/disabled through software
  - Triangle wave modulation up to 100 kHz modulation frequency
  - Programmable modulation depth (0% to 2% modulation depth)
  - Programmable modulation frequency dependent on reference frequency

1. EBI not available on all packages and is not available, as a master, for customer.

The eTPU2 includes these distinctive features:

- 32 channels; each channel associated with one input and one output signal
  - Enhanced input digital filters on the input pins for improved noise immunity
  - Identical, orthogonal channels: each channel can perform any time function. Each time function can be assigned to more than one channel at a given time, so each signal can have any functionality.
  - Each channel has an event mechanism which supports single and double action functionality in various combinations. It includes two 24-bit capture registers, two 24-bit match registers, 24-bit greater-equal and equal-only comparators.
  - Input and output signal states visible from the host
- 2 independent 24-bit time bases for channel synchronization:
  - First time base clocked by system clock with programmable prescale division from 2 to 512 (in steps of 2), or by output of second time base prescaler
  - Second time base counter can work as a continuous angle counter, enabling angle based applications to match angle instead of time
  - Both time bases can be exported to the eMIOS timer module
  - Both time bases visible from the host
- Event-triggered microengine:
  - Fixed-length instruction execution in two-system-clock microcycle
  - 14 KB of code memory (SCM)
  - 3 KB of parameter (data) RAM (SPRAM)
  - Parallel execution of data memory, ALU, channel control and flow control sub-instructions in selected combinations
  - 32-bit microengine registers and 24-bit wide ALU, with 1 microcycle addition and subtraction, absolute value, bitwise logical operations on 24-bit, 16-bit, or byte operands, single-bit manipulation, shift operations, sign extension and conditional execution
  - Additional 24-bit Multiply/MAC/Divide unit which supports all signed/unsigned Multiply/MAC combinations, and unsigned 24-bit divide. The MAC/Divide unit works in parallel with the regular microcode commands.
- Resource sharing features support channel use of common channel registers, memory and microengine time:
  - Hardware scheduler works as a “task management” unit, dispatching event service routines by predefined, host-configured priority
  - Automatic channel context switch when a “task switch” occurs, that is, one function thread ends and another begins to service a request from other channel: channel-specific registers, flags and parameter base address are automatically loaded for the next serviced channel
  - SPRAM shared between host CPU and eTPU2, supporting communication either between channels and host or inter-channel
  - Hardware implementation of four semaphores support coherent parameter sharing between both eTPU engines
  - Dual-parameter coherency hardware support allows atomic access to two parameters by host
- Test and development support features:
  - Nexus Class 1 debug, supporting single-step execution, arbitrary microinstruction execution, hardware breakpoints and watchpoints on several conditions
  - Software breakpoints
  - SCM continuous signature-check built-in self test (MISC - multiple input signature calculator), runs concurrently with eTPU2 normal operation

be used primarily as a vehicle serial data bus, meeting the specific requirements of this field: real-time processing, reliable operation in the EMI environment of a vehicle, cost-effectiveness and required bandwidth. Each FlexCAN module contains 64 message buffers.

The FlexCAN modules provide the following features:

- Based on and including all existing features of the Freescale TouCAN module
- Full Implementation of the CAN protocol specification, Version 2.0B
  - Standard data and remote frames
  - Extended data and remote frames
  - Zero to eight bytes data length
  - Programmable bit rate up to 1 Mbit/s
- Content-related addressing
- 64 message buffers of zero to eight bytes data length
- Individual Rx Mask Register per message buffer
- Each message buffer configurable as Rx or Tx, all supporting standard and extended messages
- Includes 1088 bytes of embedded memory for message buffer storage
- Includes 256-byte memory for storing individual Rx mask registers
- Full featured Rx FIFO with storage capacity for six frames and internal pointer handling
- Powerful Rx FIFO ID filtering, capable of matching incoming IDs against 8 extended, 16 standard or 32 partial (8 bits) IDs, with individual masking capability
- Selectable backwards compatibility with previous FlexCAN versions
- Programmable clock source to the CAN Protocol Interface, either system clock or oscillator clock
- Listen only mode capability
- Programmable loop-back mode supporting self-test operation
- 3 programmable Mask Registers
- Programmable transmit-first scheme: lowest ID, lowest buffer number or highest priority
- Time Stamp based on 16-bit free-running timer
- Global network time, synchronized by a specific message
- Maskable interrupts
- Warning interrupts when the Rx and Tx Error Counters reach 96
- Independent of the transmission medium (an external transceiver is assumed)
- Multi-master concept
- High immunity to EMI
- Short latency time due to an arbitration scheme for high-priority messages
- Low power mode, with programmable wake-up on bus activity

1.4.17 FlexRay

The MPC5644A includes one dual-channel FlexRay module that implements the FlexRay Communications System Protocol Specification, Version 2.1 Rev A. Features include:

- Single channel support
- FlexRay bus data rates of 10 Mbit/s, 8 Mbit/s, 5 Mbit/s, and 2.5 Mbit/s supported
- 128 message buffers, each configurable as:
  - Receive message buffer
  - Single buffered transmit message buffer
  - Double buffered transmit message buffer (combines two single buffered message buffer)
- 2 independent receive FIFOs

— 64-bit Censorship password register
— If the external tool writes a 64-bit password that matches the Serial Boot password stored in the internal flash shadow row, Censorship is disabled until the next system reset.

1.4.27 Development Trigger Semaphore (DTS)

MPC5644A devices include a system development feature, the Development Trigger Semaphore (DTS) module, that enables software to signal an external tool by driving a persistent (affected only by reset or an external tool) signal on an external device pin. There is a variety of ways this module can be used, including as a component of an external real-time data acquisition system

1.5 MPC5644A series architecture

1.5.1 Block diagram

Figure 1 shows a top-level block diagram of the MPC5644A series.

2.2 208 MAP BGA ballmap

	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	
A	VSS	AN9	AN11	VDDA1	VSSA1	AN1	AN5	VRH	VRL	AN27	VSSA0	AN12-SDS	MDO2	MDO0	VRC33	VSS	A
B	VDD	VSS	AN8	AN21	AN0	AN4	REFBYPC	AN22	AN25	AN28	VDDA0	AN13-SDO	MDO3	MDO1	VSS	VDD	B
C	VSTBY	VDD	VSS	AN17	AN34	AN16	AN3	AN7	AN23	AN32	AN33	AN14-SDI	AN15-FCK	VSS	MSEO0	TCK	C
D	VRC33	AN39	VDD	VSS	AN18	AN2	AN6	AN24	AN30	AN31	AN35	VDDEH7	VSS	TMS	EVTO	NC	D
E	ETPUA30	ETPUA31	AN37	VDD									NC	TDI	EVTI	MSEO1	E
F	ETPUA28	ETPUA29	ETPUA26	AN36									VDDEH6AB	TDO	MCKO	JCOMP	F
G	ETPUA24	ETPUA27	ETPUA25	ETPUA21			VSS	VSS	VSS	VSS			DSPI_B_SOUT	DSPI_B_PCS3	DSPI_B_SIN	DSPI_B_PCS0	G
H	ETPUA23	ETPUA22	ETPUA17	ETPUA18			VSS	VSS	VSS	VSS			GPIO99	DSPI_B_PCS4	DSPI_B_PCS2	DSPI_B_PCS1	H
J	ETPUA20	ETPUA19	ETPUA14	ETPUA13			VSS	VSS	VSS	VSS			DSPI_B_PCS5	SCI_A_TX	GPIO98	DSPI_B_SCK	J
K	ETPUA16	ETPUA15	ETPUA7	VDDEH1AB			VSS	VSS	VSS	VSS			CAN_C_TX	SCI_A_RX	RSTOUT	VDDREG	K
L	ETPUA12	ETPUA11	ETPUA6	TCRCLKA									SCI_B_TX	CAN_C_RX	WKPCFG	RESET	L
M	ETPUA10	ETPUA9	ETPUA1	ETPUA5									SCI_B_RX	PLLREF	BOOTCFG1	VSS	M
N	ETPUA8	ETPUA4	ETPUA0	VSS	VDD	VRC33	EMIOS2	EMIOS10	VDDEH4AB	EMIOS12	MDO7_ETPUA19_O	VRC33	VSS[1]	VRCCTL	NC	EXTAL	N
P	ETPUA3	ETPUA2	VSS	VDD	GPIO207	NC	EMIOS6	EMIOS8	MDO11_ETPUA29_O	MDO4_ETPUA2_O	MDO8_ETPUA21_O	CAN_A_TX	VDD	VSS	NC	XTAL	P
R	NC	VSS	VDD	GPIO206	EMIOS4	EMIOS3	EMIOS9	EMIOS11	EMIOS14	MDO10_ETPUA27_O	EMIOS23	CAN_A_RX	CAN_B_RX	VDD	VSS	VDDPLL	R
T	VSS	VDD	NC	EMIOS0	EMIOS1	GPIO219	MDO9_ETPUA25_O	EMIOS13	EMIOS15	MDO5_ETPUA4_O	MDO6_ETPUA13_O	CAN_B_TX	VDDE5	ENGCLK	VDD	VSS	T
	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	

[1] This pin (N13) should be tied low.

Figure 3. 208-pin MAPBGA package ballmap (viewed from above)

Table 3. MPC5644A signal properties (continued)

Name	Function[1]	PAG[2]	PCR PA Field[3]	PCR[4]	I/O Type	Voltage[5] / Pad Type[6]	Status[7]		Package pin #		
							During Reset	After Reset	176	208	324
ADDR26 DATA26 GPIO[22]	External address bus External data bus GPIO	P A2 G	001 100 000	22	I/O I/O I/O	VDDE-EH Medium	— / Up	— / Up	—	—	U2
ADDR27 DATA27 GPIO[23]	External address bus External data bus GPIO	P A2 G	001 100 000	23	I/O I/O I/O	VDDE-EH Medium	— / Up	— / Up	—	—	U3
ADDR28 DATA28 GPIO[24]	External address bus External data bus GPIO	P A2 G	001 100 000	24	I/O I/O I/O	VDDE-EH Medium	— / Up	— / Up	—	—	U4
ADDR29 DATA29 GPIO[25]	External address bus External data bus GPIO	P A2 G	001 100 000	25	I/O I/O I/O	VDDE-EH Medium	— / Up	— / Up	—	—	V1
ADDR30 ADDR6[8] DATA30 GPIO[26]	External address bus External address bus External data bus GPIO	P A1 A2 G	001 010 100 000	26	I/O O I/O I/O	VDDE-EH Medium	— / Up	— / Up	—	—	V3
ADDR31 ADDR7[8] DATA31 GPIO[27]	External address bus External address bus External data bus GPIO	P A1 A2 G	001 010 100 000	27	I/O O I/O I/O	VDDE-EH Medium	— / Up	— / Up	—	—	V4
DATA0 ADDR16 GPIO[28]	External data bus External address bus GPIO	P A1 G	001 010 000	28	I/O I/O I/O	VDDE5 Fast	— / Up	— / Up	—	—	Y5
DATA1 ADDR17 GPIO[29]	External data bus External address bus GPIO	P A1 G	001 010 000	29	I/O I/O I/O	VDDE5 Fast	— / Up	— / Up	—	—	AA5
DATA2 ADDR18 GPIO[30]	External data bus External address bus GPIO	P A1 G	001 010 000	30	I/O I/O I/O	VDDE5 Fast	— / Up	— / Up	—	—	AB5
DATA3 ADDR19 GPIO[31]	External data bus External address bus GPIO	P A1 G	001 010 000	31	I/O I/O I/O	VDDE5 Fast	— / Up	— / Up	—	—	AB6
DATA4 ADDR20 GPIO[32]	External data bus External address bus GPIO	P A1 G	001 010 000	32	I/O I/O I/O	VDDE5 Fast	— / Up	— / Up	—	—	AA6

Table 3. MPC5644A signal properties (continued)

Name	Function[1]	PAG[2]	PCR PA Field[3]	PCR[4]	I/O Type	Voltage[5] / Pad Type[6]	Status[7]		Package pin #		
							During Reset	After Reset	176	208	324
DATA5 ADDR21 GPIO[33]	External data bus External address bus GPIO	P A1 G	001 010 000	33	I/O I/O I/O	VDDE5 Fast	— / Up	— / Up	—	—	Y6
DATA6 ADDR22 GPIO[34]	External data bus External address bus GPIO	P A1 G	001 010 000	34	I/O I/O I/O	VDDE5 Fast	— / Up	— / Up	—	—	W6
DATA7 ADDR23 GPIO[35]	External data bus External address bus GPIO	P A1 G	001 010 000	35	I/O I/O I/O	VDDE5 Fast	— / Up	— / Up	—	—	AB7
DATA8 ADDR24 GPIO[36]	External data bus External address bus GPIO	P A1 G	001 010 000	36	I/O I/O I/O	VDDE5 Fast	— / Up	— / Up	—	—	AA7
DATA9 ADDR25 GPIO[37]	External data bus External address bus GPIO	P A1 G	001 010 000	37	I/O I/O I/O	VDDE5 Fast	— / Up	— / Up	—	—	Y7
DATA10 ADDR26 GPIO[38]	External data bus External address bus GPIO	P A1 G	001 010 000	38	I/O I/O I/O	VDDE5 Fast	— / Up	— / Up	—	—	W7
DATA11 ADDR27 GPIO[39]	External data bus External address bus GPIO	P A1 G	001 010 000	39	I/O I/O I/O	VDDE5 Fast	— / Up	— / Up	—	—	AB8
DATA12 ADDR28 GPIO[40]	External data bus External address bus GPIO	P A1 G	001 010 000	40	I/O I/O I/O	VDDE5 Fast	— / Up	— / Up	—	—	AA8
DATA13 ADDR29 GPIO[41]	External data bus External address bus GPIO	P A1 G	001 010 000	41	I/O I/O I/O	VDDE5 Fast	— / Up	— / Up	—	—	Y8
DATA14 ADDR30 GPIO[42]	External data bus External address bus GPIO	P A1 G	001 010 000	42	I/O I/O I/O	VDDE5 Fast	— / Up	— / Up	—	—	W9
DATA15 ADDR31 GPIO[43]	External data bus External address bus GPIO	P A1 G	001 010 000	43	I/O I/O I/O	VDDE5 Fast	— / Up	— / Up	—	—	Y9
RD_$\overline{WR}$ GPIO[62]	External read/write GPIO	P G	01 00	62	I/O I/O	VDDE2 Fast	— / Up	— / Up	—	—	J4

Table 3. MPC5644A signal properties (continued)

Name	Function[1]	PAG[2]	PCR PA Field[3]	PCR[4]	I/O Type	Voltage[5] / Pad Type[6]	Status[7]		Package pin #		
							During Reset	After Reset	176	208	324
CAL_DATA[2]	Calibration data bus	P	01	341	I/O	VDDE12 Fast	— / Up	— / Up	—	—	—
CAL_DATA[3]	Calibration data bus	P	01	341	I/O	VDDE12 Fast	— / Up	— / Up	—	—	—
CAL_DATA[4]	Calibration data bus	P	01	341	I/O	VDDE12 Fast	— / Up	— / Up	—	—	—
CAL_DATA[5]	Calibration data bus	P	01	341	I/O	VDDE12 Fast	— / Up	— / Up	—	—	—
CAL_DATA[6]	Calibration data bus	P	01	341	I/O	VDDE12 Fast	— / Up	— / Up	—	—	—
CAL_DATA[7]	Calibration data bus	P	01	341	I/O	VDDE12 Fast	— / Up	— / Up	—	—	—
CAL_DATA[8]	Calibration data bus	P	01	341	I/O	VDDE12 Fast	— / Up	— / Up	—	—	—
CAL_DATA[9]	Calibration data bus	P	01	341	I/O	VDDE12 Fast	— / Up	— / Up	—	—	—
CAL_DATA[10]	Calibration data bus	P	01	341	I/O	VDDE12 Fast	— / Up	— / Up	—	—	—
CAL_DATA[11]	Calibration data bus	P	01	341	I/O	VDDE12 Fast	— / Up	— / Up	—	—	—
CAL_DATA[12]	Calibration data bus	P	01	341	I/O	VDDE12 Fast	— / Up	— / Up	—	—	—
CAL_DATA[13]	Calibration data bus	P	01	341	I/O	VDDE12 Fast	— / Up	— / Up	—	—	—
CAL_DATA[14]	Calibration data bus	P	01	341	I/O	VDDE12 Fast	— / Up	— / Up	—	—	—
CAL_DATA[15]	Calibration data bus	P	01	341	I/O	VDDE12 Fast	— / Up	— / Up	—	—	—
CAL_RD_WR	Calibration read/write enable	P	01	342	O	VDDE12 Fast		— / —	—	—	—
CAL_$\overline{WE}$[0]/$\overline{BE}$[0]	Calibration write/byte enable	P	01	342	O	VDDE12 Fast		— / —	—	—	—

Table 3. MPC5644A signal properties (continued)

Name	Function[1]	PAG[2]	PCR PA Field[3]	PCR[4]	I/O Type	Voltage[5] / Pad Type[6]	Status[7]		Package pin #		
							During Reset	After Reset	176	208	324
TCK	JTAG test clock input	P	01	—	I	VDDEH7 MultiV[12]	TCK / Down	TCK / Down	128	C16	D21
TDI	JTAG test data input	P	01	232	I	VDDEH7 MultiV[12]	TDI / Up	TDI / Up	130	E14	D22
TDO	JTAG test data output	P	01	228	O	VDDEH7 MultiV[12]	TDO / Up	TDO / Up	123	F14	E21
TMS	JTAG test mode select input	P	01	—	I	VDDEH7 MultiV[12]	TMS / Up	TMS / Up	131	D14	E20
JCOMP	JTAG TAP controller enable	P	01	—	I	VDDEH7 MultiV[12]	JCOMP / Down	JCOMP / Down	121	F16	F20
FlexCAN											
CAN_A_TX SCI_A_TX GPIO[83]	FlexCAN A TX eSCI A TX GPIO	P A1 G	01 10 00	83	O O I/O	VDDEH6 Slow	— / Up	— / Up	81	P12	AB19
CAN_A_RX SCI_A_RX GPIO[84]	FlexCAN A RX eSCI A RX GPIO	P A1 G	01 10 00	84	I I I/O	VDDEH6 Slow	— / Up	— / Up	82	R12	Y19
CAN_B_TX DSPI_C_PCS[3] SCI_C_TX GPIO[85]	FlexCAN B TX DSPI C peripheral chip select eSCI C TX GPIO	P A1 A2 G	001 010 100 000	85	O O O I/O	VDDEH6 Slow	— / Up	— / Up	88	T12	Y22
CAN_B_RX DSPI_C_PCS[4] SCI_C_RX GPIO[86]	FlexCAN B RX DSPI C peripheral chip select eSCI C RX GPIO	P A1 A2 G	001 010 100 000	86	I O I I/O	VDDEH6 Slow	— / Up	— / Up	89	R13	W21
CAN_C_TX DSPI_D_PCS[3] GPIO[87]	FlexCAN C TX DSPI D peripheral chip select GPIO	P A1 G	01 10 00	87	O O I/O	VDDEH6 Medium	— / Up	— / Up	101	K13	P19
CAN_C_RX DSPI_D_PCS[4] GPIO[88]	FlexCAN C RX DSPI D peripheral chip select GPIO	P A1 G	01 10 00	88	I O I/O	VDDEH6 Slow	— / Up	— / Up	98	L14	V20
eSCI											

Table 3. MPC5644A signal properties (continued)

Name	Function[1]	PAG[2]	PCR PA Field[3]	PCR[4]	I/O Type	Voltage[5] / Pad Type[6]	Status[7]		Package pin #		
							During Reset	After Reset	176	208	324
ETPUA17 DSPI_D_PCS[2] RCH3_A GPIO[131]	eTPU A channel DSPI D peripheral chip select Reaction channel 3A GPIO	P A1 A2 G	001 010 100 000	131	I/O O O I/O	VDDEH1 Slow	— / WKPCFG	— / WKPCFG	38	H3	Y1
ETPUA18 DSPI_D_PCS[3] RCH4_A GPIO[132]	eTPU A channel DSPI D peripheral chip select Reaction channel 4A GPIO	P A1 A2 G	001 010 100 000	132	I/O O O I/O	VDDEH1 Slow	— / WKPCFG	— / WKPCFG	37	H4	W3
ETPUA19 DSPI_D_PCS[4] RCH5_A GPIO[133]	eTPU A channel DSPI D peripheral chip select Reaction channel 5A GPIO	P A1 A2 G	001 010 100 000	133	I/O O O I/O	VDDEH1 Slow	— / WKPCFG	— / WKPCFG	36	J2	W2
ETPUA20 IRQ[8] RCH0_B FR_A_TX GPIO[134]	eTPU A channel External interrupt request Reaction channel 0B Flexray TX data channel A GPIO	P A1 A2 A3 G	0001 0010 0100 1000 0000	134	I/O I O O I/O	VDDEH1 Slow	— / WKPCFG	— / WKPCFG	35	J1	W1
ETPUA21 IRQ[9] RCH0_C FR_A_RX GPIO[135]	eTPU A channel External interrupt request Reaction channel 0C Flexray RX channel A GPIO	P A1 A2 A3 G	0001 0010 0100 1000 0000	135	I/O I O I I/O	VDDEH1 Slow	— / WKPCFG	— / WKPCFG	34	G4	N4
ETPUA22 IRQ[10] ETPUA17_O[8] GPIO[136]	eTPU A channel External interrupt request eTPU A channel (output only) GPIO	P A1 A2 G	001 010 100 000	136	I/O I O I/O	VDDEH1 Slow	— / WKPCFG	— / WKPCFG	32	H2	N3
ETPUA23 IRQ[11] ETPUA21_O[8] FR_A_TX_EN GPIO[137]	eTPU A channel External interrupt request eTPU A channel (output only) Flexray ch. A TX enable GPIO	P A1 A2 A3 G	0001 0010 0100 1000 0000	137	I/O I O O I/O	VDDEH1 Slow	— / WKPCFG	— / WKPCFG	30	H1	M1
ETPUA24 IRQ[12] DSPI_C_SCK_LV DS- GPIO[138]	eTPU A channel External interrupt request LVDS negative DSPI clock GPIO	P A1 A2 G	001 010 100 000	138	I/O I O I/O	VDDEH1 Slow + LVDS	— / WKPCFG	— / WKPCFG	28	G1	M2

- B. Joiner and V. Adams, “Measurement and Simulation of Junction to Board Thermal Resistance and Its Application in Thermal Modeling,” Proceedings of SemiTherm, San Diego, 1999, pp. 212-220.

3.4 EMI (electromagnetic interference) characteristics

Table 12. EMI Testing Specifications[1]

Symbol	Parameter	Conditions	Clocks	Frequency Range	Level (Max)	Unit
Radiated emissions, electric field	V_{RE_TEM}	V_{DDREG} = 5.25 V; T_A = 25 °C 150 kHz – 30 MHz RBW 9 kHz, Step Size 5 kHz 30 MHz – 1 GHz - RBW 120 kHz, Step Size 80 kHz	16 MHz crystal 40 MHz bus No PLL frequency modulation	150 kHz – 50 MHz	20	dBμV
				50 – 150 MHz	20	
				150 – 500 MHz	26	
				500 – 1000 MHz	26	
				IEC Level	K	—
				SAE Level	3	—
			16 MHz crystal 40 MHz bus ±2% PLL frequency modulation	150 kHz– 50 MHz	13	dBμV
				50 – 150 MHz	13	
				150 – 500 MHz	11	
				500 – 1000 MHz	13	
				IEC Level	L	—
				SAE Level	2	—

1 EMI testing and I/O port waveforms per SAE J1752/3 issued 1995-03 and IEC 61967-2.

3.5 Electrostatic discharge (ESD) characteristics

Table 13. ESD ratings[1,2]

Symbol		Parameter	Conditions	Value	Unit
—	SR	ESD for Human Body Model (HBM)	—	2000	V
R1	SR	HBM circuit description	—	1500	Ω
C	SR		—	100	pF
—	SR	ESD for field induced charge Model (FDCM)	All pins	500	V
			Corner pins	750	
—	SR	Number of pulses per pin	Positive pulses (HBM)	1	—
			Negative pulses (HBM)	1	—
—	SR	Number of pulses	—	1	—

1 All ESD testing is in conformity with CDF-AEC-Q100 Stress Test Qualification for Automotive Grade Integrated Circuits.

Table 17. MPC5644A External network specification

External Network Parameter	Min	Typ	Max	Comment
Re	0.252Ω	0.280Ω	0.308Ω	+/-10%
Creg		10μF		It depends on external Vreg.
Cc	5μF	10μF	13.5μF	X7R, -50%/+35%
Rc	1.1Ω		5.6Ω	May or may not be required. It depends on the allowable power dissipation of T1.

3.6.3 Recommended power transistors

The following NPN transistors are recommended for use with the on-chip voltage regulator controller: ON Semiconductor™ BCP68T1 or NJD2873 as well as Philips Semiconductor™ BCP68. The collector of the external transistor is preferably connected to the same voltage supply source as the output stage of the regulator.

Table 18. Recommended operating characteristics

Symbol	Parameter	Value	Unit
h_{FE} (β)	DC current gain (Beta)	60 – 550	—
P_D	Absolute minimum power dissipation	>1.0 (1.5 preferred)	W
I_{CMaxDC}	Minimum peak collector current	1.0	A
VCE_{SAT}	Collector-to-emitter saturation voltage	200 – 600[1]	mV
V_{BE}	Base-to-emitter voltage	0.4 – 1.0	V

[1] Adjust resistor at bipolar transistor collector for 3.3 V/5.0 V to avoid VCE < VCE_{SAT}.

3.7 Power up/down sequencing

There is no power sequencing required among power sources during power up and power down, in order to operate within specification.

Although there are no power up/down sequencing requirements to prevent issues such as latch-up or excessive current spikes the state of the I/O pins during power up/down varies according to Table 19 for all pins with fast pads, and Table 20 for all pins with medium, slow, and multi-voltage pads.

Table 19. Power sequence pin states (fast pads)

V_{DDE}	V_{RC33}	V_{DD}	Pad State
LOW	X	X	LOW
V_{DDE}	LOW	X	HIGH
V_{DDE}	V_{RC33}	LOW	HIGH IMPEDANCE
V_{DDE}	V_{RC33}	V_{DD}	FUNCTIONAL

Table 20. Power sequence pin states (medium, slow, and multi-voltage pads)

V_{DDEH}	V_{DD}	Pad State
LOW	X	LOW
V_{DDEH}	LOW	HIGH IMPEDANCE
V_{DDEH}	V_{DD}	FUNCTIONAL

3.8 DC electrical specifications

Table 21. DC electrical specifications

Symbol		C	Parameter	Conditions	Value			Unit
					min	typ	max	
V_{DD}	SR	—	Core supply voltage	—	1.14		1.32	V
V_{DDE}	SR	—	I/O supply voltage	—	1.62		3.6	V
V_{DDEH}	SR	—	I/O supply voltage	—	3.0		5.25	V
V_{DDE-EH}	SR	—	I/O supply voltage	—	3.0		5.25	V
V_{RC33}	SR	—	3.3 V regulated voltage[1]	—	3.0	—	3.6	V
V_{DDA}	SR	—	Analog supply voltage	—	4.75[2]	—	5.25	V
V_{INDC}	SR	—	Analog input voltage	—	V_{SSA}-0.3	—	V_{DDA}+0.3	V
$V_{SS} – V_{SSA}$	SR	—	V_{SS} differential voltage	—	–100	—	100	mV
V_{RL}	SR	—	Analog reference low voltage	—	V_{SSA}	—	V_{SSA}+0.1	V
$V_{RL} – V_{SSA}$	SR	—	VRL differential voltage	—	–100	—	100	mV
V_{RH}	SR	—	Analog reference high voltage	—	V_{DDA}-0.1	—	V_{DDA}	V
$V_{RH} – V_{RL}$	SR	—	V_{REF} differential voltage	—	4.75	—	5.25	V
V_{DDF}	SR	—	Flash operating voltage[3]	—	1.14	—	1.32	V
V_{FLASH}[4]	SR	—	Flash read voltage	—	3.0	—	3.6	V
V_{STBY}	SR	—	SRAM standby voltage	Unregulated mode	0.95	—	1.2	V
			Keep-out Range: 1.2V–2V	Regulated mode	2.0	—	5.5	

Table 26. PLLMRFM electrical specifications

(V_{DDPLL} = 1.08 V to 3.6 V, V_{SS} = V_{SSPLL} = 0 V, T_A = T_L to T_H) (continued)

Symbol		C	Parameter	Conditions	Value		Unit
					min	max	
V_{IHEXT}	CC	T	EXTAL input high voltage	Crystal Mode[12]	Vxtal + 0.4	—	V
		T		External Reference[12, 13]	V_{RC33} /2 + 0.4	V_{RC33}	
V_{ILEXT}	CC	T	EXTAL input low voltage	Crystal Mode[12]	—	Vxtal - 0.4	V
		T		External Reference[12, 13]	0	V_{RC33} /2 - 0.4	
—	CC	T	XTAL load capacitance[10]	4 MHz	5	30	pF
				8 MHz	5	26	
				12 MHz	5	23	
				16 MHz	5	19	
				20 MHz	5	16	
				40 MHz	5	8	
t_{lpll}	CC	P	PLL lock time [10, 14]	—	—	200	µs
t_{dc}	CC	T	Duty cycle of reference	—	40	60	%
f_{LCK}	CC	T	Frequency LOCK range	—	–6	6	% f_{sys}
f_{UL}	CC	T	Frequency un-LOCK range	—	–18	18	% f_{sys}
f_{CS} f_{DS}	CC	D	Modulation Depth	Center spread	±0.25	±4.0	% f_{sys}
		D		Down Spread	–0.5	–8.0	
f_{MOD}	CC	D	Modulation frequency[15]	—	—	100	kHz

1 Considering operation with PLL not bypassed.

2 All internal registers retain data at 0 Hz.

3 “Loss of Reference Frequency” window is the reference frequency range outside of which the PLL is in self clocked mode.

4 Self clocked mode frequency is the frequency that the PLL operates at when the reference frequency falls outside the f_{LOR} window.

5 f_{VCO} self clock range is 20–150 MHz. f_{SCM} represents f_{SYS} after PLL output divider (ERFD) of 2 through 16 in enhanced mode.

6 This value is determined by the crystal manufacturer and board design.

7 Jitter is the average deviation from the programmed frequency measured over the specified interval at maximum f_{SYS}. Measurements are made with the device powered by filtered supplies and clocked by a stable external clock signal. Noise injected into the PLL circuitry via V_{DDPLL} and V_{SSPLL} and variation in crystal oscillator frequency increase the C_{JITTER} percentage for a given interval.

Table 29. eQADC single ended conversion specifications (operating)

Symbol		C	Parameter	Value		Unit
				min	max	
OFFNC	CC	C	Offset error without calibration	0	160	Counts
OFFWC	CC	C	Offset error with calibration	–4	4	Counts
GAINNC	CC	C	Full scale gain error without calibration	–160	0	Counts
GAINWC	CC	C	Full scale gain error with calibration	–4	4	Counts
I_{INJ}	CC	T	Disruptive input injection current [1, 2, 3, 4]	–3	3	mA
E_{INJ}	CC	T	Incremental error due to injection current[5,6]	–4	4	Counts
TUE8	CC	C	Total unadjusted error (TUE) at 8 MHz	–4	4[6]	Counts
TUE16	CC	C	Total unadjusted error at 16 MHz	–8	8	Counts

1 Below disruptive current conditions, the channel being stressed has conversion values of 0x3FF for analog inputs greater then V_{RH} and 0x0 for values less then V_{RL}. Other channels are not affected by non-disruptive conditions.

2 Exceeding limit may cause conversion error on stressed channels and on unstressed channels. Transitions within the limit do not affect device reliability or cause permanent damage.

3 Input must be current limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values using $V_{POSCLAMP} = V_{DDA} + 0.5$ V and $V_{NEGCLAMP} = – 0.3$ V, then use the larger of the calculated values.

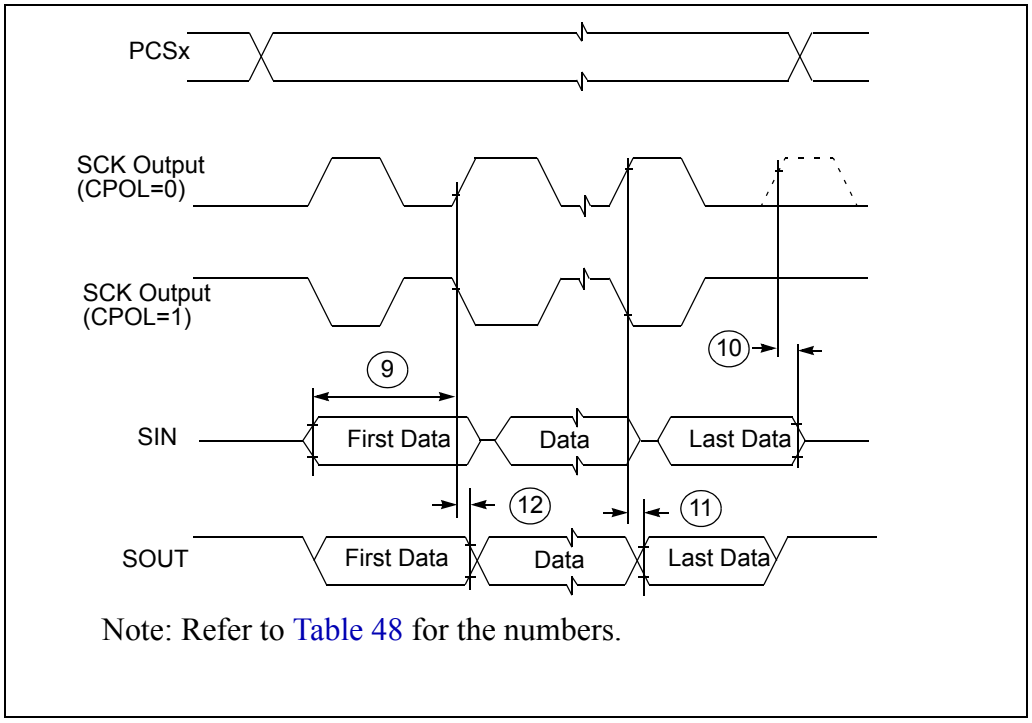
4 Condition applies to two adjacent pins at injection limits.

5 Performance expected with production silicon.

6 All channels have same 10 kΩ < Rs < 100 kΩ; Channel under test has Rs=10 kΩ; I_{INJ}=I_{INJMAX},I_{INJMIN}

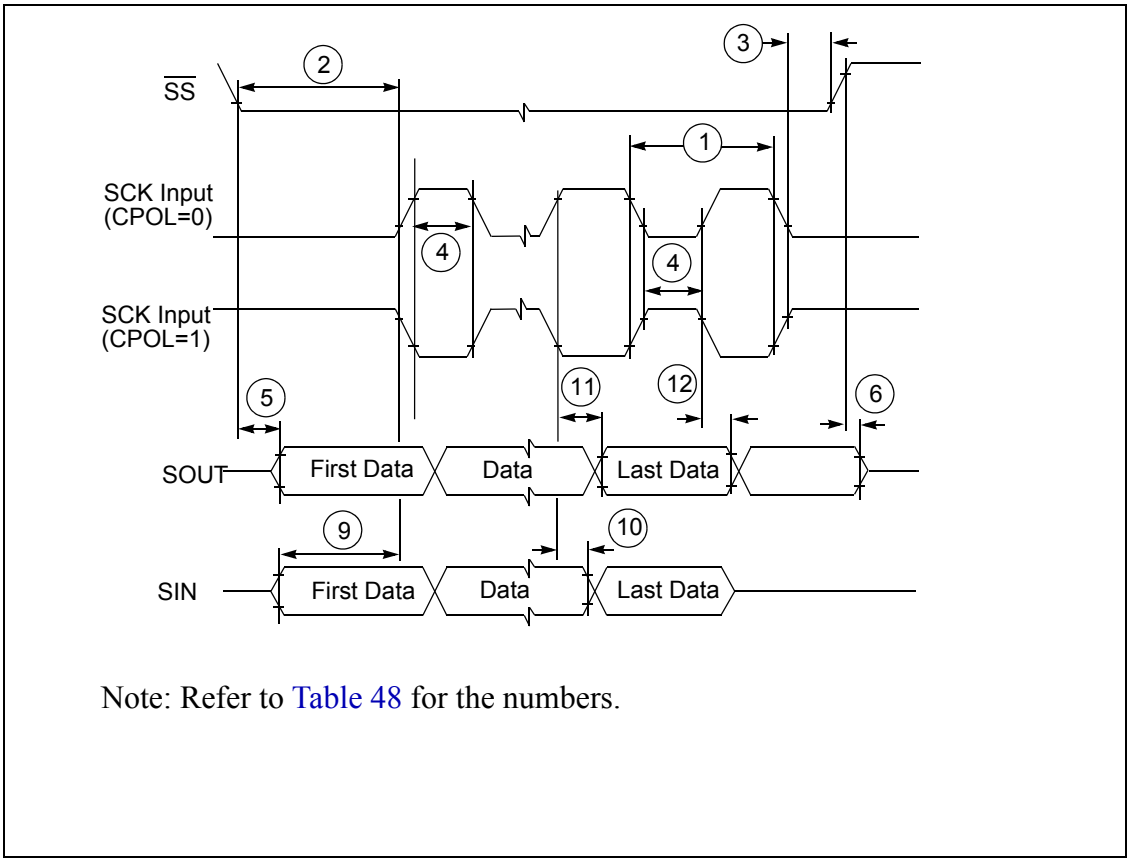
Table 30. eQADC differential ended conversion specifications (operating)

Symbol		C	Parameter		Value		Unit
					min	max	
GAINVGA1[1]	CC	–	Variable gain amplifier accuracy (gain=1)[2]				
	CC	C	INL	8 MHz ADC	–4	4	Counts[3]
	CC	C		16 MHz ADC	–8	8	Counts
	CC	C	DNL	8 MHz ADC	–3[4]	3[4]	Counts
	CC	C		16 MHz ADC	–3[4]	3[4]	Counts



Note: Refer to Table 48 for the numbers.

Figure 28. DSPI modified transfer format timing — master, CPHA = 1



Note: Refer to Table 48 for the numbers.

Figure 29. DSPI modified transfer format timing — slave, CPHA =0

3.17.9 eQADC SSI timing

Table 49. eQADC SSI timing characteristics (pads at 3.3 V or at 5.0 V)[1]

CLOAD = 25 pF on all outputs. Pad drive strength set to maximum.								
#	**Symbol**		**C**	**Rating**	**Min**	**Typ**	**Max**	**Unit**
1	f_{FCK}	CC	D	FCK Frequency [2, 3]	1/17		1/2	f_{SYS_CLK}
1	t_{FCK}	CC	D	FCK Period (t_{FCK} = 1/ f_{FCK})	2		17	t_{SYS_CLK}
2	t_{FCKHT}	CC	D	Clock (FCK) High Time	t_{SYS_CLK} − 6.5		$_{9*}$ t_{SYS_CLK} + 6.5	ns
3	t_{FCKLT}	CC	D	Clock (FCK) Low Time	t_{SYS_CLK} − 6.5		$_{8*}$ t_{SYS_CLK} + 6.5	ns
4	t_{SDS_LL}	CC	D	SDS Lead/Lag Time	-7.5		7.5	ns
5	t_{SDO_LL}	CC	D	SDO Lead/Lag Time	-7.5		7.5	ns
6	t_{DVFE}	CC	D	Data Valid from FCK Falling Edge (t_{FCKLT}+t_{SDO_LL})	1			ns
7	t_{EQ_SU}	CC	D	eQADC Data Setup Time (Inputs)	22			ns
8	t_{EQ_HO}	CC	D	eQADC Data Hold Time (Inputs)	1			ns

1 SS timing specified at f_{SYS} = 80 MHz, V_{DD} = 1.14 V to 1.32 V, V_{DDEH} = 4.5 V to 5.5 V, T_A = T_L to T_H, and C_L = 50 pF with SRC = 0b00.

2 Maximum operating frequency is highly dependent on track delays, master pad delays, and slave pad delays.

3 FCK duty is not 50% when it is generated through the division of the system clock by an odd number.

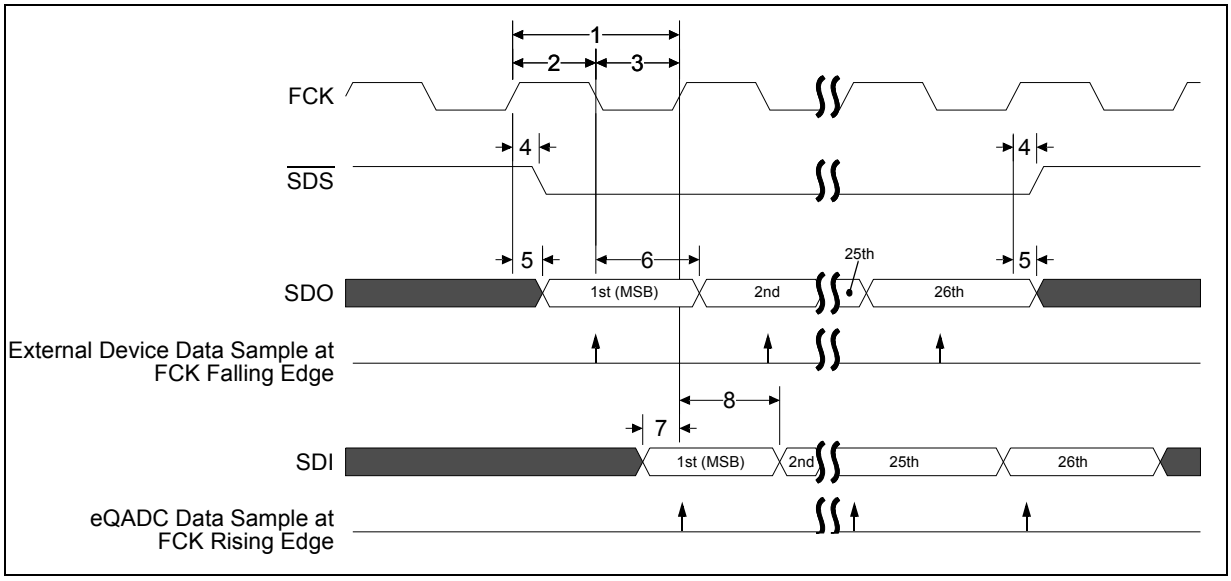


Figure 32. eQADC SSI timing

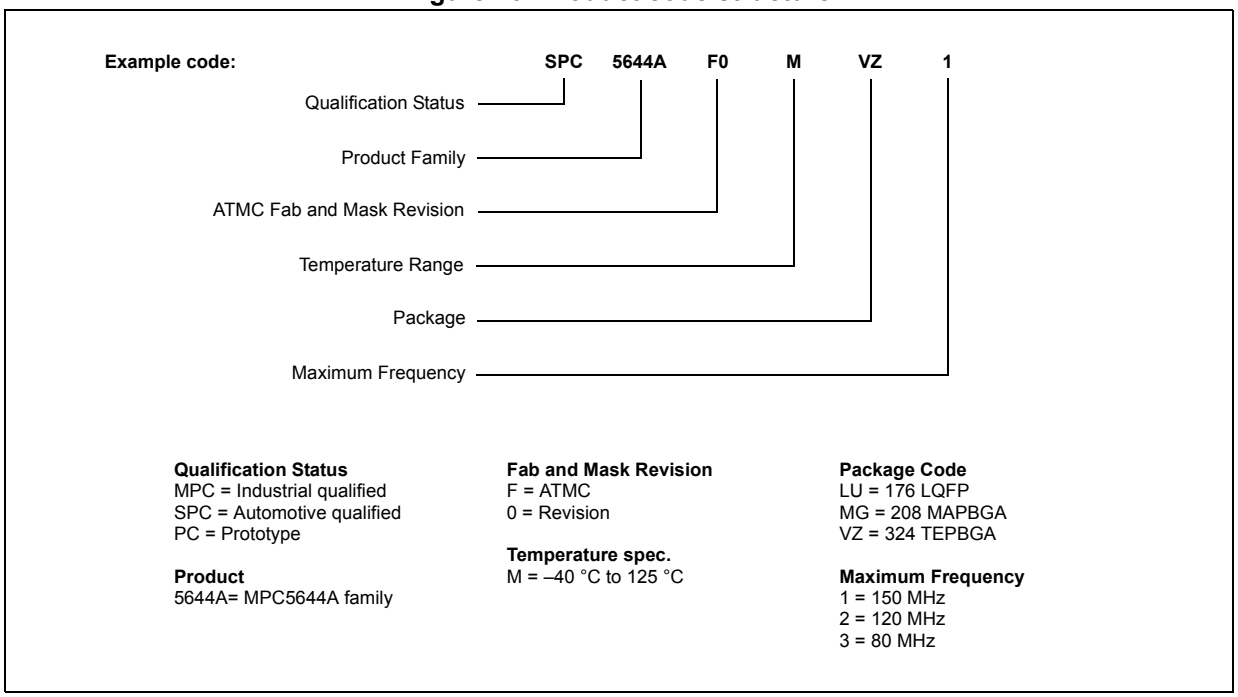
5 Ordering information

Table 52 shows the orderable part numbers for the MPC5644A series.

Table 52. Orderable part number summary

Part number	Flash/SRAM	Package	Speed (MHz)
SPC5643AF0MLU3	3 MB/192 KB	176LQFP (Pb free)	80
SPC5643AF0MMG3	3 MB/192 KB	208MAPBGA(Pb free)	80
SPC5643AF0MVZ3	3 MB/192 KB	324PBGA (Pb free)	80
SPC5643AF0MLU2	3 MB/192 KB	176LQFP (Pb free)	120
SPC5643AF0MMG2	3 MB/192 KB	208MAPBGA (Pb free)	120
SPC5643AF0MVZ2	3 MB/192 KB	324PBGA (Pb free)	120
SPC5643AF0MLU1	3 MB/192 KB	176LQFP (Pb free)	150
SPC5643AF0MMG1	3 MB/192 KB	208MAPBGA (Pb free)	150
SPC5643AF0MVZ1	3 MB/192 KB	324PBGA (Pb free)	150
SPC5644AF0MLU3	4 MB/192 KB	176 LQFP (Pb free)	80
SPC5644AF0MMG3	4 MB/192 KB	208 MAPBGA (Pb free)	80
SPC5644AF0MVZ3	4 MB/192 KB	324 TEPBGA (Pb free)	80
SPC5644AF0MLU2	4 MB/192 KB	176 LQFP (Pb free)	120
SPC5644AF0MMG2	4 MB/192 KB	208 MAPBGA (Pb free)	120
SPC5644AF0MVZ2	4 MB/192 KB	324 TEPBGA (Pb free)	120
SPC5644AF0MLU1	4 MB/192 KB	176 LQFP (Pb free)	150
SPC5644AF0MMG1	4 MB/192 KB	208 MAPBGA (Pb free)	150
SPC5644AF0MVZ1	4 MB/192 KB	324 TEPBGA (Pb free)	150

Figure 40. Product code structure



6 Document revision history

Table 53 summarizes revisions to this document.

Table 53. Revision history

Revision	Date	Substantive changes
Rev. 1	4/2008	Initial release

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